

10079269
02/19/02

PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10079269	FILING DATE 02/19/2002	CLASS 117	SUBCLASS 8.1	GAU 1765	EXAMINER SUNG J
**APPLICANTS: Hooper Stewart; Barnes Jennifer; Bousquet Valerie; Heffernan Jonathan;					
**CONTINUING DATA VERIFIED:					
** FOREIGN APPLICATIONS VERIFIED: UNITED KINGDOM 0104598.8 02/23/2001					
PG-PUB <input type="checkbox"/>		DO NOT PUBLISH <input type="checkbox"/>		RESCIND <input type="checkbox"/>	
Foreign priority claimed <input type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 conditions met <input type="checkbox"/> yes <input type="checkbox"/> no Verified and Acknowledged Examiners's initials				ATTORNEY DOCKET NO YAMAP0800US	
TITLE : Method of growing a semiconductor multi-layer structure					

U.S. DEPT. OF COMM./PAT. & TM-PTO-436L (Rev. 12-94)

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
		Assistant Examiner	
ISSUE FEE		Total Claims	
Amount Due	Date Paid	Print Claim for O.G.	
		DRAWING	
		Sheets Drwg.	Figs. Drwg.
		Print Fig.	
		Primary Examiner	
		Application Examiner	
<input type="checkbox"/> TERMINAL DISCLAIMER		PREPARED FOR ISSUE WARNING: The information disclosed herein may be restricted. Unauthorized disclosure may be prohibited by the United States Code Title 35, Sections 122, 181 and 368, Possession outside the U.S. Patent & Trademark Office is restricted to authorized employees and contractors only.	

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